

Electrical Datasheet GA060TH65-CAU

Silicon Carbide Thyristor

V_{FBM} 6500 V = 60 A I_{T(AVM)} \mathbf{Q}_{rr} 2.95 µC

Features

- 6500 V Asymmetric SiC NPNP Thyristor
- 210 °C operating temperature
- Fast turn on characteristics
- Lowest in class Q_{rr}/I_{T(AVM)}

- Applications
 Grid Tied Solar Inverters
- Wind Power Inverters
- HVDC Power Conversion
- Utility Scale Power Conversion
- Trigger Circuits/Ignition Circuits





maximum ratingo				
Parameter	Symbol	Conditions	Values	Unit
Repetitive peak forward voltage	$V_{_{FBM}}$	T _j = 25 °C	6500	V
Repetitive peak reverse voltage	V_{RBM}	T _j = 25 °C	50	V
Maximum average on-state current	I _{T(AVM)}	T _C ≤ 120 °C	60	Α
RMS on-state current	I _{T(RMS)}	T _C ≤ 120 °C	104	Α
Operating and storage temperature	T,, T,,		-55 to 210	°C

Electrical Characteristics

Parameter	Symbol	Conditions	Values		1114	
			min.	typ.	max.	Unit
Maximum peak on state voltage	$V_{\text{KA(ON)}}$	I _K = -60 A, T _j = 25 °C		-3.90		V
		$I_{\kappa} = -60 \text{ A}, T_{j} = 150 ^{\circ}\text{C}$		-3.70		
Anode-cathode threshold voltage	$V_{KA(TO)}$	T _j = 25 °C (150 °C)		-3.1(-2.8)		V
Anode-cathode slope resistance	R _{AK}	T _j = 25 °C (150 °C), I _K = -60 A		9.4(9.5)		mΩ
Leakage current	I _L	V _{KA} = -6500 V, V _{GA} = 0 V, T _i = 25 °C		20		μΑ
		$V_{KA} = -6500 \text{ V}, V_{GA} = 0 \text{ V}, T_{i} = 150 ^{\circ}\text{C}$		50		
Gate trigger current	I _{GT}	$T_{p} = 25 ^{\circ}\text{C}, t_{p} = 10 \mu\text{s}$		-100		mA
Holding current	I _H	T _i = 25 °C		tbd		mA
Rise time	t _R	I _G = -3 A, V _{KA} = -2200 V		170		ns
Delay time	$t_{_{\rm D}}$	$I_{K} = -60 \text{ A}, T_{j} = 25 ^{\circ}\text{C}$		45		ns
Reverse recovery charge	Q _{rr}			2.95		μC
Recovered charge, 50% chord	Q_{ra}	$dI/dt = 360 \text{ A/us}, I_{K} = -60 \text{ A}, V_{KA} = 20 \text{ V}$		1.6		μC
Reverse recovery current	I	$dV/dt(re-app) = -362 V/us, T_i = 25 °C$		15		Α
Circuit commutated turn-off time	t	•		6.7		μs

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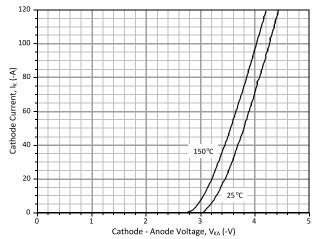


Figure 1: Typical On State Characteristics

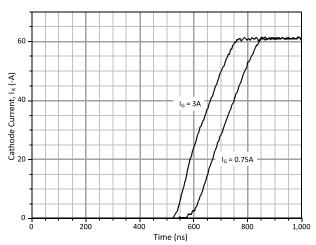


Figure 5: Typical Turn On Characteristics at 25 °C

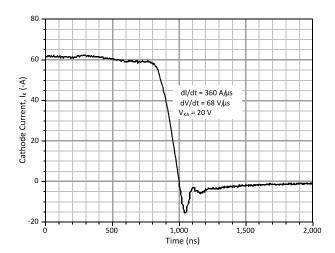


Figure 7: Typical Reverse Recovery Characteristics at 25 °C

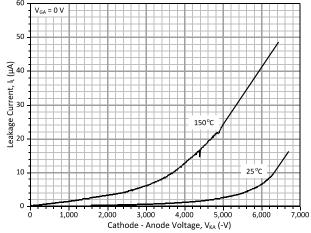


Figure 2: Typical Forward Blocking Characteristics

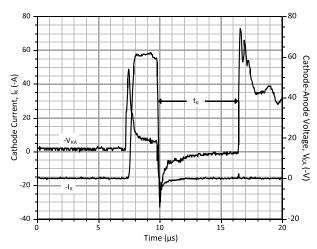


Figure 6: Typical Turn Off Characteristics at 25 °C



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Revision History						
Date	Revision	Comments	Supersedes			
2010/11/07	1	First generation release				

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